TOSHIBA TLYE160A

TOSHIBA LED LAMP InGaA&P YELLOW LIGHT EMISSION

TLYE160A

PANEL CIRCUIT INDICATOR

- 3.1 mm DIAMETER (T1)
- InGaA&P YELLOW LED
- All Plastic Mold Type.
- Colorless Clear Lens
- Low Drive Current, High Intensity Yellow Light Emission Recommended Forward Current: IF = 15~20 mA (DC)
- All Plastic Molded Lens, Provides an Excellent ON-OFF Contrast Ratio.
- Fast Response Time, Capable of Pulse Operation.
- High Power Luminous Intensity
- APPLICATIONS: Suitable for Safety equipment. Outdoor displays.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Forward Current (DC)	$\mathbf{I_F}$	50	mA
Reverse Voltage	v_{R}	4	V
Power Dissipation	$P_{\mathbf{D}}$	125	mW
Operating Temperature Range	$T_{ m opr}$	-30~85	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-40~120	°C

Ø 3.8 ± 0.2 Ø 3.1 ± 0.2 3.74 ± 0.2 0.7MAX 0.7MAX 0.45 જ 1. ANODE 2. CATHODE **JEDEC EIAJ TOSHIBA** 4-3E1A

Unit in mm

Weight: 0.14 g

ELECTRICAL AND OPTICAL CHARACTERISTICS (Ta = 25°C)

CHARA	ACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Forward Vol	ltage	$ m V_{f F}$	$I_{ m F}=20{ m mA}$	_	2.1	2.5	V
Reverse Cur	rent	$_{ m I_R}$	$V_R = 4 V$	_	_	50	μ A
Luminous	TLYE160A	- I _V	$I_{ m F}=20~{ m mA}~{ m (Note)}$	476	2300	_	mcd
Intensity	TLYE160A (ST)			850	_	4140	
Peak Emissi	on Wavelength	$\lambda_{\mathbf{p}}$	$I_{ m F}=20{ m mA}$	_	590	_	nm
Spectral Lin	e Half Width	Δλ	$I_{ m F}=20{ m mA}$		13		nm
Dominant W	/avelength	$^{\lambda}\mathbf{d}$	$I_{ m F}=20{ m mA}$	_	587		nm

(Note): Lamps are classified into the following ranks according to their luminous intensity. Measurement tolerance for each limit is $\pm 15\%$.

R: 560-1120 mcd, S: 1000-2000 mcd, T: 1800-3600 mcd.

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● Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic

garbage.

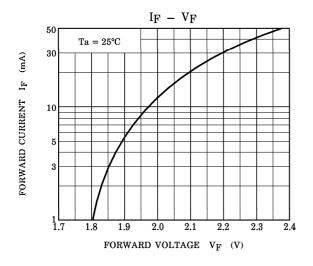
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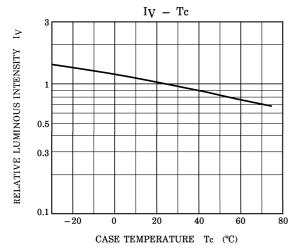
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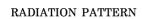
PRECAUTION

Please be careful of the followings

- Soldering temperature: 260°C max Soldering time: 3 s max (Soldering portion of lead: up to 2 mm from the body of the device)
- If the lead is formed, the lead should be formed up to 5 mm from the body of the device without forming stress to the resin. Soldering should be performed after lead forming.
- This visible LED lamp also emits some IR light. If a photodetector is located near the LED lamp, please ensure that it will not be affected by this IR light.







 $Ta = 25^{\circ}C$

